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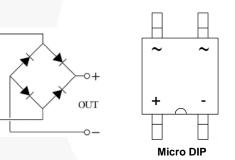


October 2013

MDB6S / MDB8S / MDB10S 1 A, MicroDIP, Single-Phase Bridge Rectifiers

Features

- Low Package Profile: 1.60 mm (max)
 Small Area Requirements: 35 mm²
- Efficient V_E
 - 0.935 V (Typ) at 1 A
 - 1.165 V (Typ) at 5 A
- IF(AV) = 1.0 A
- IFSM = 30 A
- · Glass Passivated Junctions
- RoHS Compliant
- Halogen Free
- UL Certification: E352360



Description

With the ever pressing need to improve power supply efficiency and reliability, the MDBxS family is focused on offering a best in class small form factor combined with best in class efficient rectifier performance.

The "S" family offers industry leading balance of efficiency, size, and cost. They offer designers improved efficiency by achieving an industry leading V_F of 0.935 V Typ. at 1 A 25 °C, and a V_F of 1.165 V Typ. at 5 A 25 °C. These lower V_F values offer roughly a 5% efficiency improvement over measured competitive same form factor devices. This lower V_F vs. competitive devices results in cooler and more efficient power supply operation.

The design supports a 30 A $I_{\rm FSM}$ rating to absorb high surge currents and offers rated breakdown voltages up to 1000 V.

Finally, the MDBxS family achieves all this in a small form factor micro-dip package - offering a max height of 1.6 mm, and requiring only 35 mm² of board space.

Ordering Information

Part Number	Marking	Package	Packing Method
MDB6S	MDB6S		
MDB8S	MDB8S	Micro DIP	Tape and Reel
MDB10S	MDB10S		

Absolute Maximum Ratings

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only. Values are at $T_A = 25\,^{\circ}\text{C}$ unless otherwise noted.

Symbol	Parameter	Value			Units
	T didilictor	MDB6S	MDB8S	MDB10S	Oilles
V_{RRM}	Maximum Repetitive Peak Reverse Voltage	600	800	1000	V
V _{RMS}	Maximum RMS Voltage	420	560	700	V
V _{DC}	Maximum DC Blocking Voltage	600	800	1000	V
I _{F(AV)}	Average Rectified Forward Current (1) 1.0			Α	
I _{FSM}	Peak Forward Surge Current (2)	30		Α	
I ² t	I ² t Rating for fusing (t < 8.3 ms)	3.735		A ² S	
T_J	Operating Junction Temperature Range	-55 to +150		°C	
T _{STG}	Storage Temperature Range	-55 to +150		°C	

Notes:

- 1. 60 Hz sine wave, R-load, $T_A = 25$ °C on FR-4 PCB.
- 2. 60 Hz sine wave, Non-repetitive 1 cycle peak value, T_J = 25°C.

Thermal Characteristics(3)

Symbol	Parameter			Units
$R_{ heta JA}$	Thermal Resistance, Junction-Ambient	Measurement with Dual Dice	250	°C/W
		Measurement with Single Die	150	°C/W
ΨJL	Thermal Characterization, Junction to Lead	Measured at Anode pin	57	°C/W
		Measured at Cathode pin	15	°C/W

Note:

3. Device mounted on FR-4 PCB with board size = 76.2 mm x 114.3 mm (JESD51-3 standards).

Electrical Characteristics

Values are at T_A = 25°C unless otherwise specified.

Symbol	Parameter	Test condition	Value	Units
V _F	Maximum Forward Voltage	I _F = 1 A, Pulse measurement, Per diode	1.1	V
I _R	Maximum Reverse Current	At V _{RRM} , Pulse measurement, Per diode	10	μА
CJ	Typical Junction Capacitance	V _R = 4 V, f = 1 MHz	10	pF

Typical Performance Characteristics

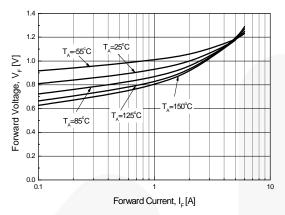


Figure 1. Forward Voltage vs Forward Current (Per diode)

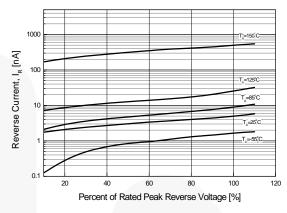


Figure 2. Typical Reverse Current Characteristics (Per Diode)

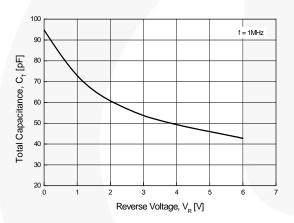
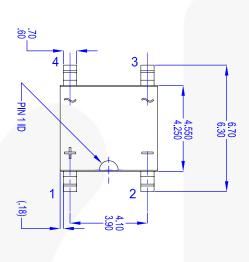
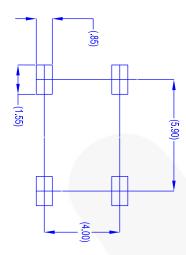


Figure 3. Total Capacitance

Physical Dimension

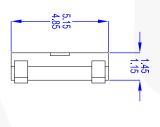
Micro-DIP



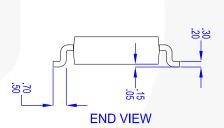


TOP VIEW

LAND PATTERN RECOMMENDATION



SIDE VIEW



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Figure 4. 4-LEAD, MIRCRO SURFACE MOUNT, 1.3 x 4 x 5 mm (Active)

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Definition of Terms

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Preliminary	First Production	Datasheet contains preliminary data; supplementary data will be published at a later date. Fairchild Semiconductor reserves the right to make changes at any time without notice to improve design.
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